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RFMD(R) Commences Volume Production of WCDMA/HSPA+ Power Amplifiers for Smartphones and 3G Devices

RF720x Product Family Mates With Leading 3G Reference Designs from Qualcomm And Other Leading Open Market Chipset Suppliers

BARCELONA, Spain, Feb 15, 2010 /PRNewswire via COMTEX News Network/ -- RF Micro Devices, Inc. (Nasdaq: RFMD), a global leader in the design and manufacture of high-performance radio frequency components and compound semiconductor technologies, today announced it has commenced high-volume production of its RF720x WCDMA/HSPA+ power amplifiers (PAs). RFMD's RF720x product family is comprised of seven high performance PAs designed for smartphones and 3G devices implementing mode-specific, band-specific front end architectures. The RF720x product family accommodates all major WCDMA/HSPA+ bands and band combinations and is optimized to mate with reference designs from Qualcomm as well as other leading open market 3G chipset suppliers.

Eric Creviston, president of RFMD's Cellular Products Group (CPG), said, "RFMD's innovative RF720x product family delivers unmatched ease of implementation and is optimized to mate with the leading open-market 3G chipset reference designs. Accordingly, we anticipate the RF720x product family will extend RFMD's leadership in 3G while supporting our customer diversification goals, particularly in Korea, China and Taiwan. RFMD is currently forecasting double-digit growth in 3G in calendar 2010, based upon existing customer design activity."

RFMD's mode-specific/band-specific RF720x product family covers all major 3G frequencies (1-6, 8-11) and provides customers with leading performance and superior design flexibility. Each RF720x PA is designed with digitally controlled power modes that optimize performance to increase battery life in both 3G voice and 3G data operation. Additionally, the RF720x family leverages leading-edge functional density to integrate critical functions into the PA, thereby significantly reducing the board area required for front end implementations while lowering mobile device bill-of-material (BOM) costs.

RFMD's product portfolio for 3G applications accommodates all major RF architectures, including existing mode-specific/band-specific and mode-specific/multi-band architectures as well as emerging multimode/multi-band, converged architectures. RFMD also supplies a broad portfolio of 2G/2.5G power amplifier-based and switch-based components optimized for 3G handsets, providing a comprehensive RF product portfolio covering the entire cellular front end.

RFMD offers the mobile device industry's broadest and most innovative portfolio of radio frequency components, including cellular power amplifier modules, cellular transmit modules, cellular switch and filter modules, and front ends for Wi-Fi, WiMAX and GPS applications. RFMD's product portfolio is on display at the 2010 Mobile World Congress in Barcelona, Spain, February 15 to February 18.

Availability and Pricing

Production quantities of the RF720x family are available immediately. Pricing is available upon request by contacting an RFMD sales representative or by visiting www.rfmd.com/purchase.

About RFMD

RF Micro Devices, Inc. (Nasdaq: RFMD) is a global leader in the design and manufacture of high-performance radio frequency components and compound semiconductor technologies. RFMD's products enable worldwide mobility, provide enhanced connectivity and support advanced functionality in the cellular handset, wireless infrastructure, wireless local area network (WLAN), CATV/broadband and aerospace and defense markets. RFMD is recognized for its diverse portfolio of semiconductor technologies and RF systems expertise and is a preferred supplier to the world's leading mobile device, customer premises and communications equipment providers.

Headquartered in Greensboro, N.C., RFMD is an ISO 9001- and ISO 14001-certified manufacturer with worldwide engineering, design, sales and service facilities. RFMD is traded on the NASDAQ Global Select Market under the symbol RFMD. For more information, please visit RFMD's web site at www.rfmd.com.

This press release includes "forward-looking statements" within the meaning of the safe harbor provisions of the Private

Securities Litigation Reform Act of 1995. These forward-looking statements include, but are not limited to, statements about our plans, objectives, representations and contentions and are not historical facts and typically are identified by use of terms such as "may," "will," "should," "could," "expect," "plan," "anticipate," "believe," "estimate," "predict," "potential," "continue" and similar words, although some forward-looking statements are expressed differently. You should be aware that the forward-looking statements included herein represent management's current judgment and expectations, but our actual results, events and performance could differ materially from those expressed or implied by forward-looking statements. We do not intend to update any of these forward-looking statements or publicly announce the results of any revisions to these forward-looking statements, other than as is required under the federal securities laws. RF Micro Devices' business is subject to numerous risks and uncertainties, including risks associated with the impact of global macroeconomic and credit conditions on our business and the business of our suppliers and customers, variability in operating results, the rate of growth and development of wireless markets, risks associated with the reduced investment in our wireless systems business, our ability to execute on our plans to consolidate or relocate manufacturing operations, our reliance on inclusion in third party reference designs for a portion of our revenue, our ability to manage channel partner and customer relationships, risks associated with the operation of our wafer fabrication facilities, molecular beam epitaxy facility, assembly facility and test and tape and reel facilities, our ability to complete acquisitions and integrate acquired companies, including the risk that we may not realize expected synergies from our business combinations, our ability to attract and retain skilled personnel and develop leaders, variability in production yields, raw material costs and availability, our ability to reduce costs and improve margins in response to declining average selling prices, our ability to bring new products to market, our ability to adjust production capacity in a timely fashion in response to changes in demand for our products, dependence on a limited number of customers, dependence on gallium arsenide (GaAs) for the majority of our products, and dependence on third parties. These and other risks and uncertainties, which are described in more detail in RF Micro Devices' most recent Annual Report on Form 10-K and other reports and statements filed with the Securities and Exchange Commission, could cause actual results and developments to be materially different from those expressed or implied by any of these forward-looking statements.

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